

GOLD BONDED DIODES

TYPE 1N270

- FEATURES**
- Low forward voltage drop
 - low power consumption
 - Thirty years of proven reliability
 - one million hours mean time between failures (MTBF)
 - Very low noise level
 - Metallurgically bonded

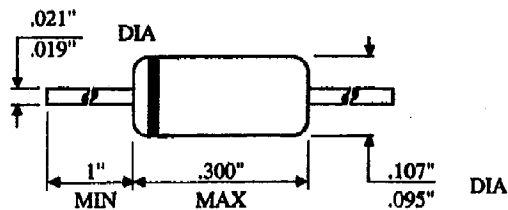
ABSOLUTE MAXIMUM RATINGS

Peak Inverse Voltage	100V	@ 25 °C
Peak Forward Current	500mA	unless
Operating Temperature Range	-65°C to 85°C	otherwise
Average Power Dissipation	80mW	specified

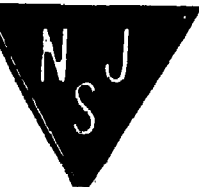
ELECTRICAL CHARACTERISTICS

	Symbol	Conditions	Min.	Max.	Unit	T °C
Peak Inverse Voltage	PIV	1mA	100		V	25°
Reverse Current	I _r	50V		100	uA	25°
Forward Voltage	V _f	200mA		1.0	V	25°

MECHANICAL



Passes all mechanical and environmental requirements of MIL-S-19500, including shock and vibration.



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